

INVENTOR INFORMATION

Inventor One Given Name:: Hongyong
Family Name:: ZHANG
Postal Address Line One:: Paresu Miyagami 302, 1-10-15, Fukamidai,
City:: Yamoto-shi
State or Province:: Kanagawa-ken
Country:: Japan
Postal or Zip Code:: 242
Citizenship Country:: Japan

CORRESPONDENCE INFORMATION

Correspondence Customer Number:: 22204
Fax One:: (703) 883-0370
Electronic Mail One:: pluther@nixonpeabody.com

APPLICATION INFORMATION

Title Line One:: METHOD FOR PRODUCING A SEMICONDUCTOR I
Title Line Two:: NTEGRATED CIRCUIT INCLUDING A THIN FILM
Title Line Three:: TRANSISTOR AND A CAPACITOR
Total Drawing Sheets:: 5
Formal Drawings?: Yes
Application Type:: Utility
Docket Number:: 740756-2395
Secrecy Order in Parent Appl.?: No

REPRESENTATIVE INFORMATION

Representative Customer Number:: 22204
Registration Number One:: 38285
Registration Number Two:: 35483
Registration Number Three:: 45285
Registration Number Four:: 27997
Registration Number Five:: 26477

CONTINUITY INFORMATION

This application is a:: DIVISION OF
> Application One:: 09/110,895
Filing Date:: 07-07-1998
Patent Number::

Which is a::DIVISION OF
>> Application Two:: 08/585,916
Filing Date:: 01-16-1996
Patent Number:: 5,814,529

093760 4400
T03T 20948660

PRIOR FOREIGN APPLICATIONS

Foreign Application One:: 07-22256

Filing Date:: 01-17-1995

Country:: Japa

Priority Claimed:: Yes

Source:: PrintEFS Version 1.0.1

07-22256